



4A TRENCH SUPER BARRIER RECTIFIER

Product Summary (@TA = +25°C)

V _{RRM} (V)	I _O (A)	V _F MAX (V)	I _{R MAX} (μ A)
60	4	0.52	150

Description and Applications

The SBRT4U60LP is a 4A, 60V single rectifier packaged in the low profile DFN3030 package. Providing low V_F and excellent high temperature stability, this device is ideal for use in general rectification applications such as:

- Bypass Diode
- Boost Diode
- Blocking Diode
- Recirculating Diode

Features and Benefits

- Reduced Ultra-Low Forward Voltage Drop (V_F); Better Efficiency and Cooler Operation
- Reduced High Temperature Reverse Leakage; Increased Reliability Against Thermal Runaway Failure in High Temperature Operation
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

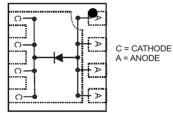
Mechanical Data

- Case: U-DFN3030-8
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu Annealed over Copper Lead Frame Solderable per MIL-STD-202, Method 208 (4)
- · Weight: 0.0172 grams (approximate)

U-DFN3030-8



Bottom View



Top View Schematic and Pin Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
SBRT4U60LP-7	U-DFN3030-8	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

T4U60 YYWW T4U60 = Product Type Marking Code YYWW = Date Code Marking Y Y= Last two digit of year (ex: 14 for 2014) WW = Week code 01 to 53



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	60	V
Average Rectified Output Current	Io	4	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	25	А

Thermal Characteristics

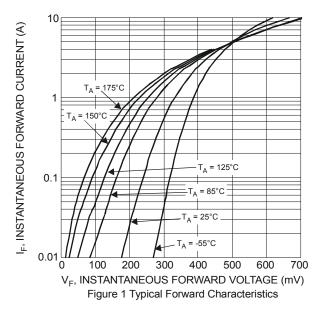
Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 5)	$R_{\theta JA}$	110	°C/W
Typical Thermal Resistance Junction to Case (Note 5)	R _{0JC}	10	°C/W
Typical Thermal Resistance Junction to Ambient (Note 6)	$R_{\theta JA}$	70	°C/W
Typical Thermal Resistance Junction to Case (Note 6)	Rejc	4	°C/W
Total Power Dissipation (Note 5)	P _{TOT}	1.4	W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C

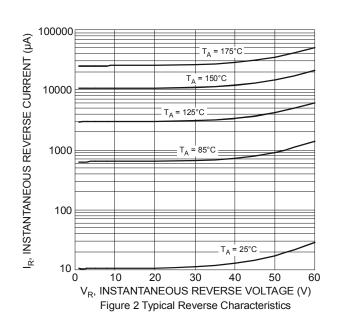
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
		_	0.38 0.46	— 0.52		$I_F = 2A$, $T_J = +25$ °C $I_F = 4A$, $T_J = +25$ °C
Forward Voltage Drop	V _F	_	0.33 0.45	_ _	V	I _F = 2A, T _J = +125°C I _F = 4A, T _J = +125°C
Leakage Current (Note 7)	I _R	_	30 6	150 —	μA mA	V _R = 60V, T _J = +25°C V _R = 60V, T _J = +125°C
Total capacitance	Ст	_	180	_	pF	V _R = 5V, f = 1MHz

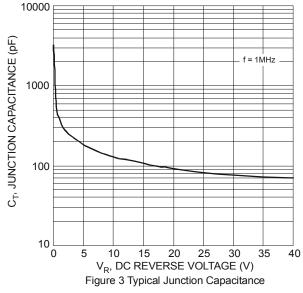
Notes:

- 5. Device mounted on FR-4 substrate, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com/datasheets/ap02001.pdf.
- 6. Device mounted on FR-4 substrate, 2 oz. Copper, 1 sq. inch Cu pad.
- 7. Short duration pulse test used to minimize self-heating effect.









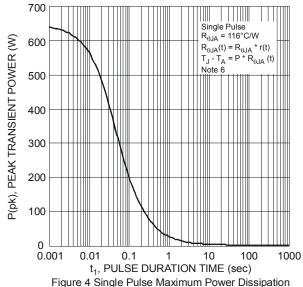


Figure 4 Single Pulse Maximum Power Dissipation

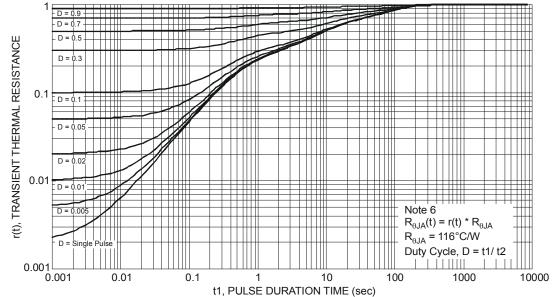
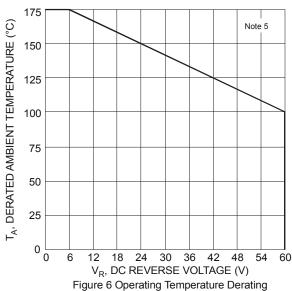


Figure 5 Transient Thermal Resistance

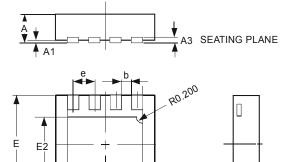


Document number: DS36791 Rev. 4 - 2



Package Outline Dimensions

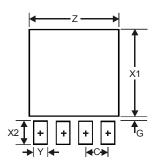
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



U-DFN3030-8				
Dim	Min	Max	Тур	
Α	0.57	0.63	0.60	
A1	0	0.05	0.02	
A3	_	_	0.15	
b	0.29	0.39	0.34	
D	2.90	3.10	3.00	
D2	2.19	2.39	2.29	
е	_	_	0.65	
Е	2.90	3.10	3.00	
E2	1.64	1.84	1.74	
L	0.30	0.60	0.45	
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



D

Dimensions	Value (in mm)
Z	2.59
G	0.11
X1	2.49
X2	0.65
Y	0.39
С	0.65



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